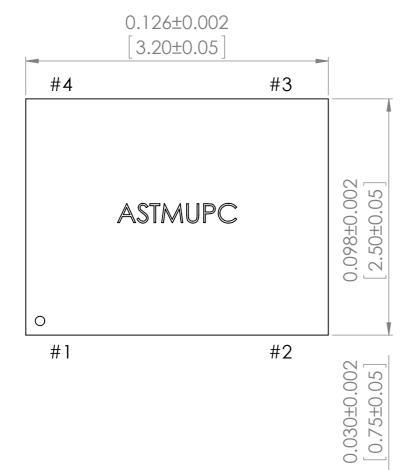
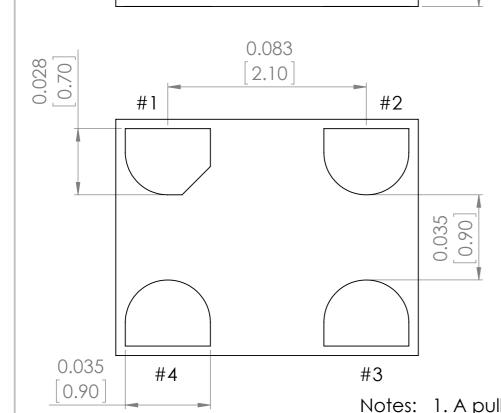
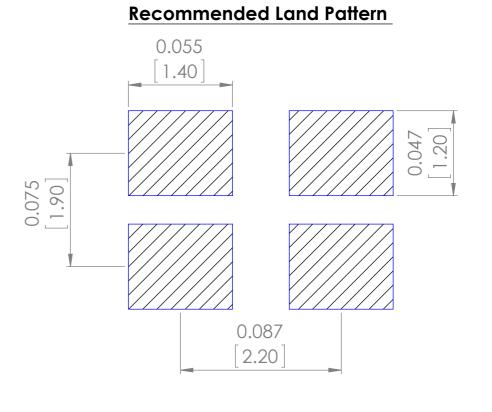


3.2 x 2.5mm Package (Option "E")





Pin	Name		Functionality	
1	OE/ST	Output Enable	H or Open (1): specified frequency output L: output is high impedance. Only output driver is disabled	
		Sidilaby	H or Open (1): specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to Istd.	
2	GND	Power	Electrical ground (2)	
3	Out	•	Oscillator clock output	
4	Vdd	Power	Power supply voltage (2)	

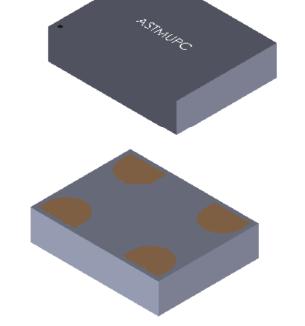


TOP PACKAGE MARKING IS FOR ILLUSTRATION PURPOSES ONLY Appracon LLC

Notes: 1. A pull-up resistor of <10kΩ between OE/ST pin and Vdd is recommended in bigh noise environment

high noise environment.

2. A capacitor value of 0.1µF between Vdd and GND is recommended.





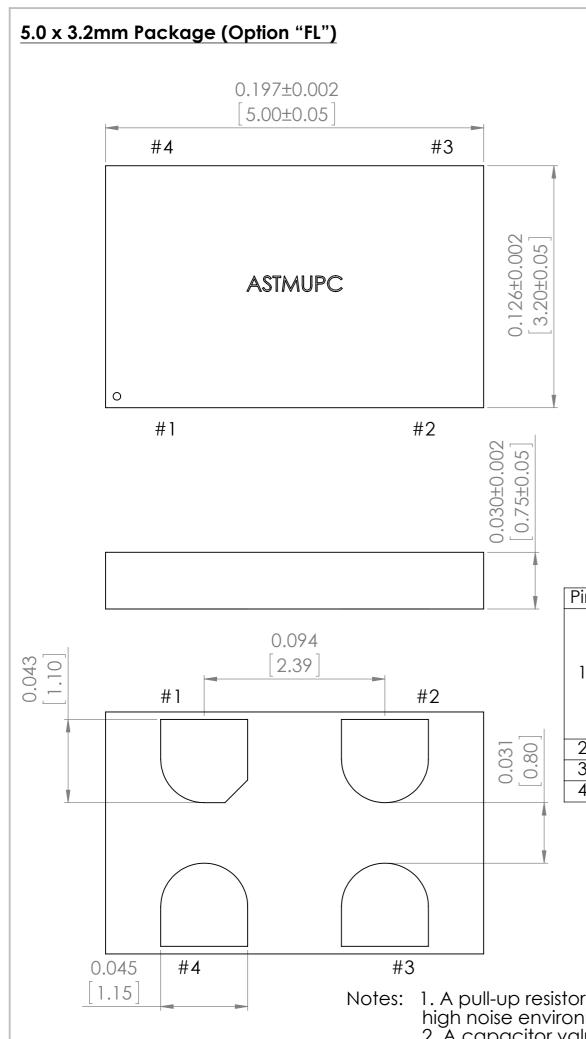
Apracon LLC. 2 Faraday, Suite#B Irvine, Ca. 92618

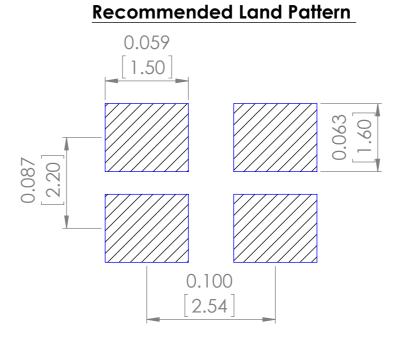
High Performance, Programmable LVCMOS SMD MEMS Oscillator

ASTMUPC

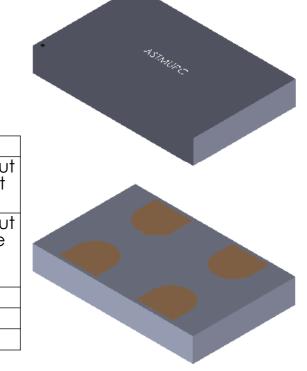
A3

25:1 SHEET 2 OF 4



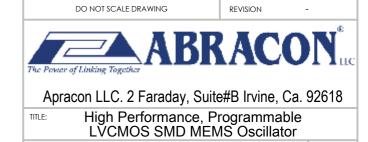


Pin	Name		Functionality	
1	OE/ST	Output Enable	H or Open (1): specified frequency output L: output is high impedance. Only output driver is disabled	
		Sidildby	H or Open (1): specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to Istd.	
2	GND	Power	Electrical ground (2)	
3	Out	Output	Oscillator clock output	
4	Vdd	Power	Power supply voltage (2)	



TOP PACKAGE MARKING IS FOR ILLUSTRATION PURPOSES ONLY

Notes: 1. A pull-up resistor of <10kΩ between OE/ST pin and Vdd is recommended in high noise environment.
2. A capacitor value of 0.1µF between Vdd and GND is recommended.



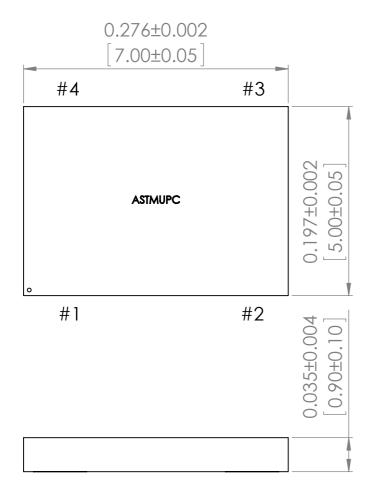
DWG NO.

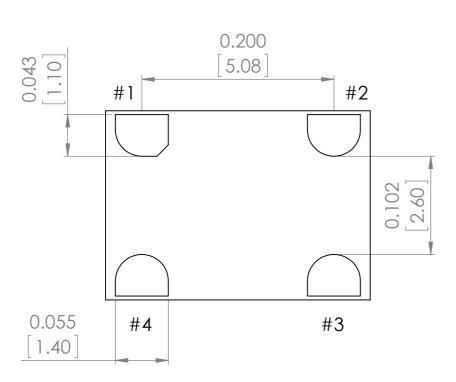
ASTMUPC

Α3

SCALE:20:1 SHEET 3 OF 4

7.0 x 5.0mm Package (Option "V")





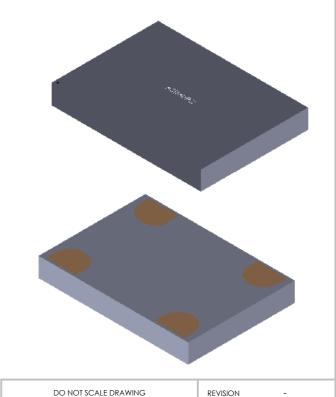
0.200 5.08 0.079 0.150 0.087 2.20

Recommended Land Pattern

Pin	Name		Functionality
1	OE/ST	Output Enable	H or Open (1): specified frequency output L: output is high impedance. Only output driver is disabled
		Standby	H or Open (1): specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to Istd.
2	GND	Power	Electrical ground (2)
3	Out	Output	Oscillator clock output
4	Vdd	Power	Power supply voltage (2)

TOP PACKAGE MARKING IS FOR ILLUSTRATION PURPOSES ONLY

Notes: 1. A pull-up resistor of <10kΩ between OE/ST pin and Vdd is recommended in high noise environment.
2. A capacitor value of 0.1μF between Vdd and GND is recommended.



ABRACON The Power of Linking Togethan						
Aprac	Apracon LLC. 2 Faraday, Suite#B Irvine, Ca. 92618 TITLE: High Performance, Programmable LVCMOS SMD MEMS Oscillator					
DWG NO.	ASTMUPC					
SCALE:10:1	Si	HEET 4 OF 4				